

Supplementary Information

Stretchable and Skin-conformable Conductors Based on Polyurethane/Laser-Induced Graphene

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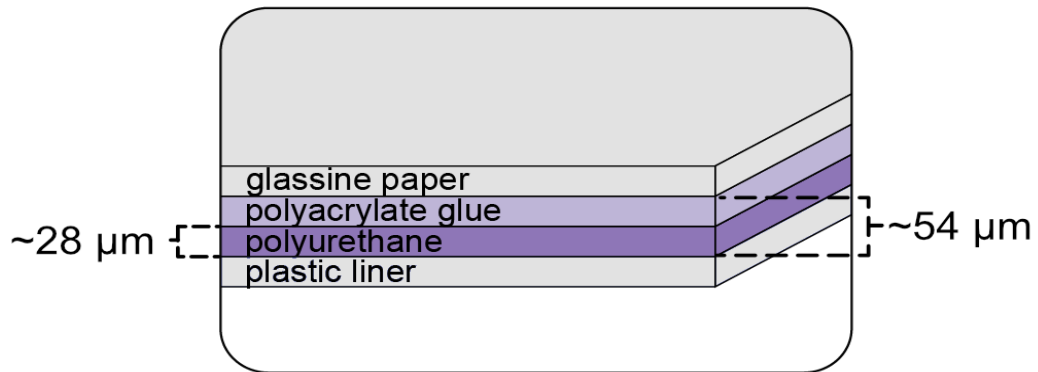


Figure S1. Schematics of MPU layers.

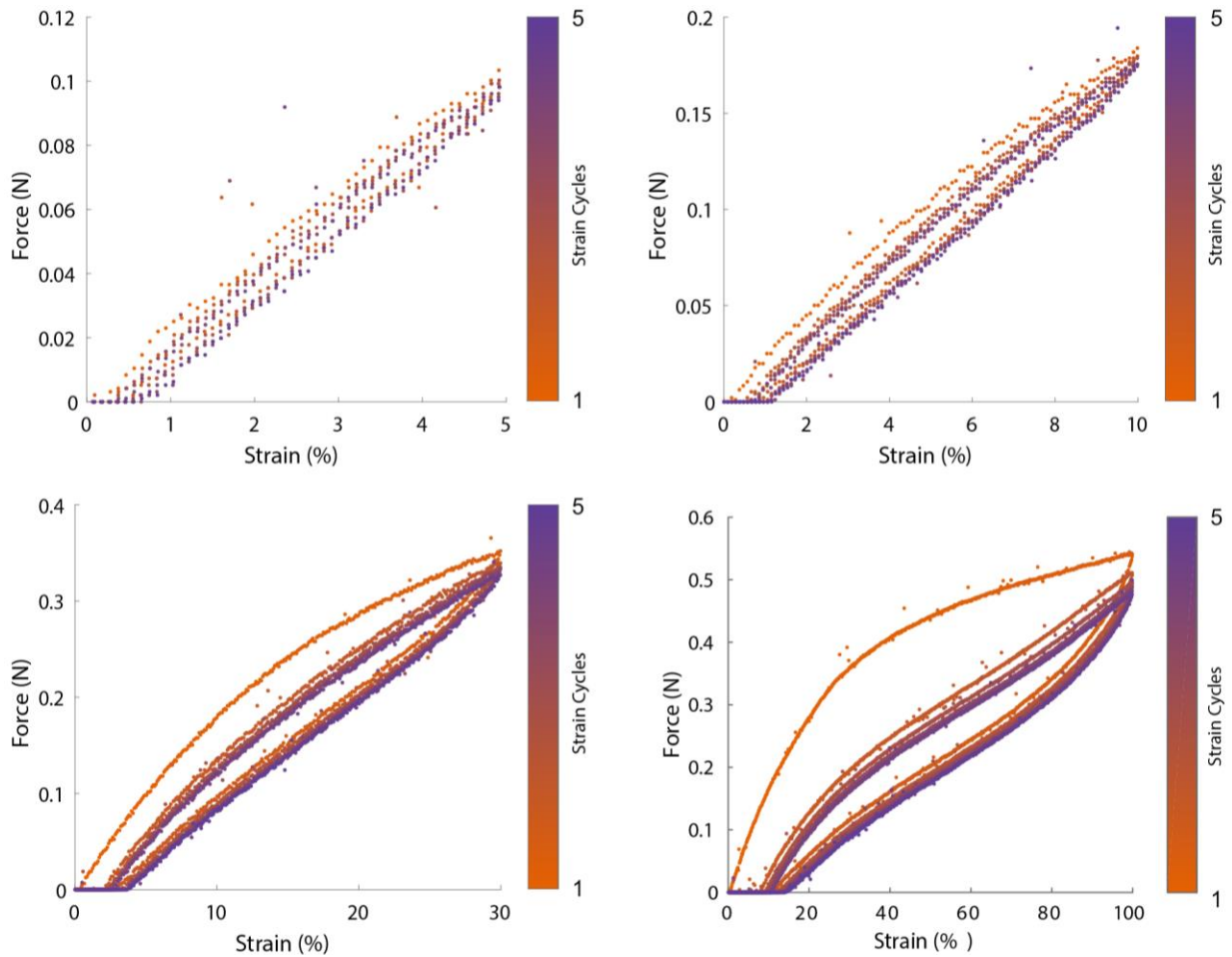


Figure S2. Force curves for MPU samples for 5%, 10%, 30% and 100% strain cycles repeated five times.

Table S1. Summary of properties of MPU.

| Property | Value |
|---------------------|--------------------------------|
| Thickness | 54±6 μm |
| Young's Modulus | (8.5 ± 0.3)MPa |
| Elongation at break | > 400% |
| WVTR ¹ | 564-648 g/m ² /24 h |

¹Water Vapor Transmission Rate (WVTR) provided by BSN medical.

Table S2. Summary of Raman spectra band parameters.

| | LIG-F | LIG-P |
|-----------------------------------|--------|--------|
| G-band position/cm ⁻¹ | 1587.3 | 1582.0 |
| G-band width/cm ⁻¹ | 56.2 | 55.4 |
| G-band intensity/counts | 98.8 | 99.4 |
| D-band position/cm ⁻¹ | 1344.6 | 1342.6 |
| D-band width/cm ⁻¹ | 77.7 | 57.8 |
| D-band intensity/counts | 85.4 | 105.1 |
| D/G-ratio | 0.86 | 1.06 |
| 2D-band position/cm ⁻¹ | 2686.7 | 2682.0 |
| 2D-band width/cm ⁻¹ | 97.7 | 99.9 |
| 2D-band intensity/counts | 40.0 | 44.3 |

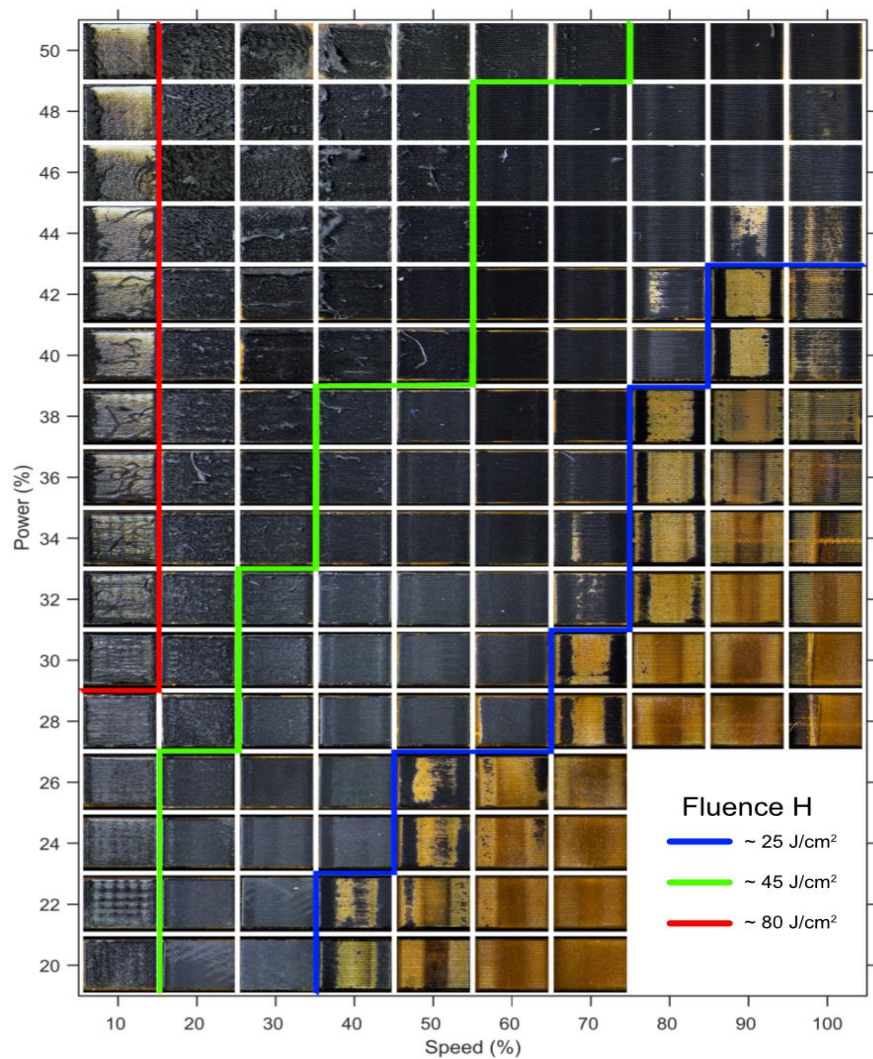


Figure S3. Map of LIG formation on PI influenced by laser power and speed parameters, resulting in different fluence H.

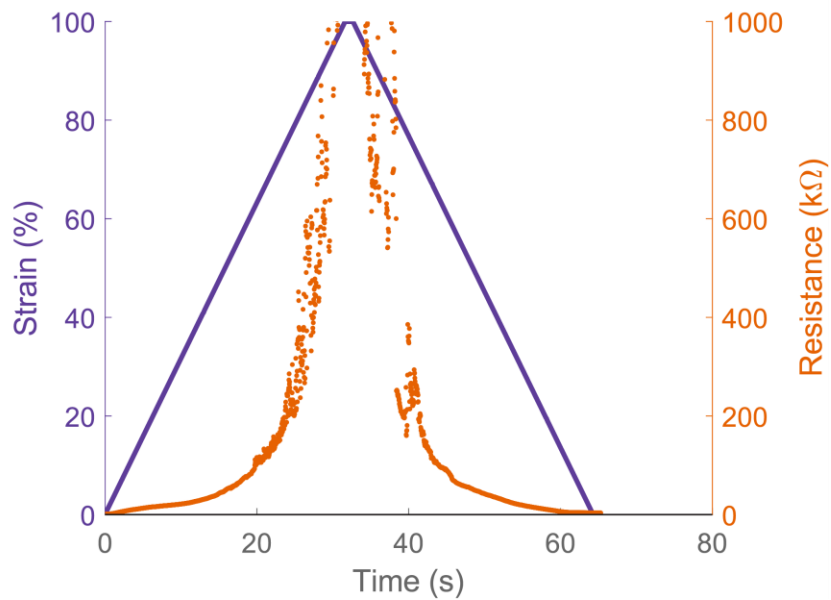


Figure S4. Stretching curve for LIG-P/MPU sample with a 100% strain/relaxation cycle and corresponding variation of electrical resistance, showing a reversible breakdown at around 60% strain (plot cut off at 1000 k Ω for better visibility).

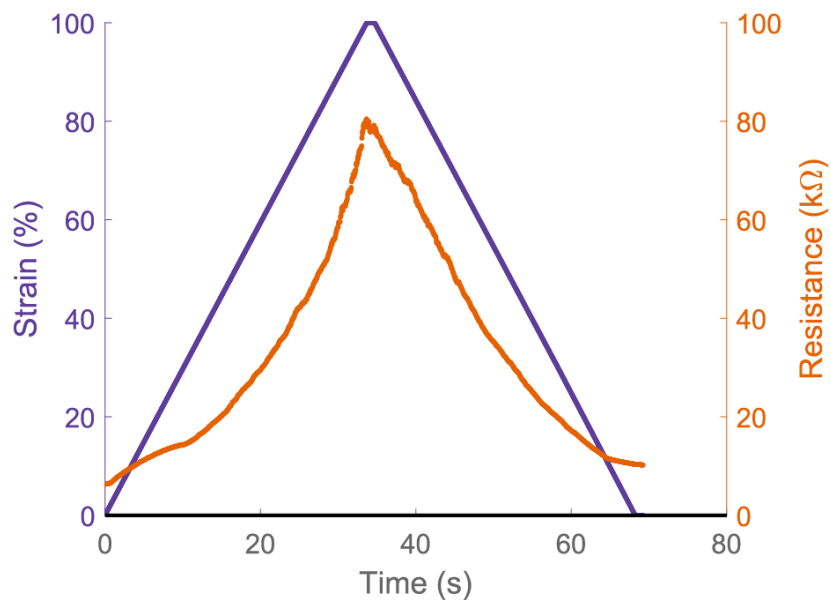


Figure S5. Stretching curve for LIG-F/MPU sample with a 100% strain/relaxation cycle and corresponding variation of electrical resistance, showing no breakdown during the full cycle.

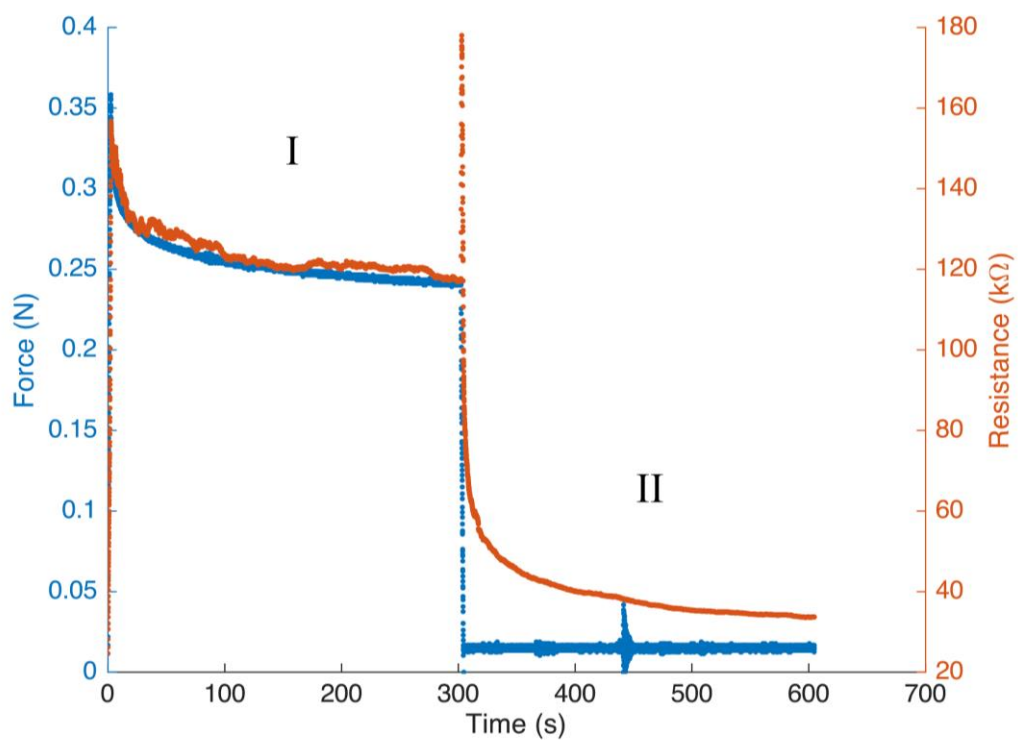


Figure S6. Stress relaxation curve from an applied 30% tensile strain on LIG-P/MPU, as used in fitting for the relaxation time constant for the I and II relaxations.

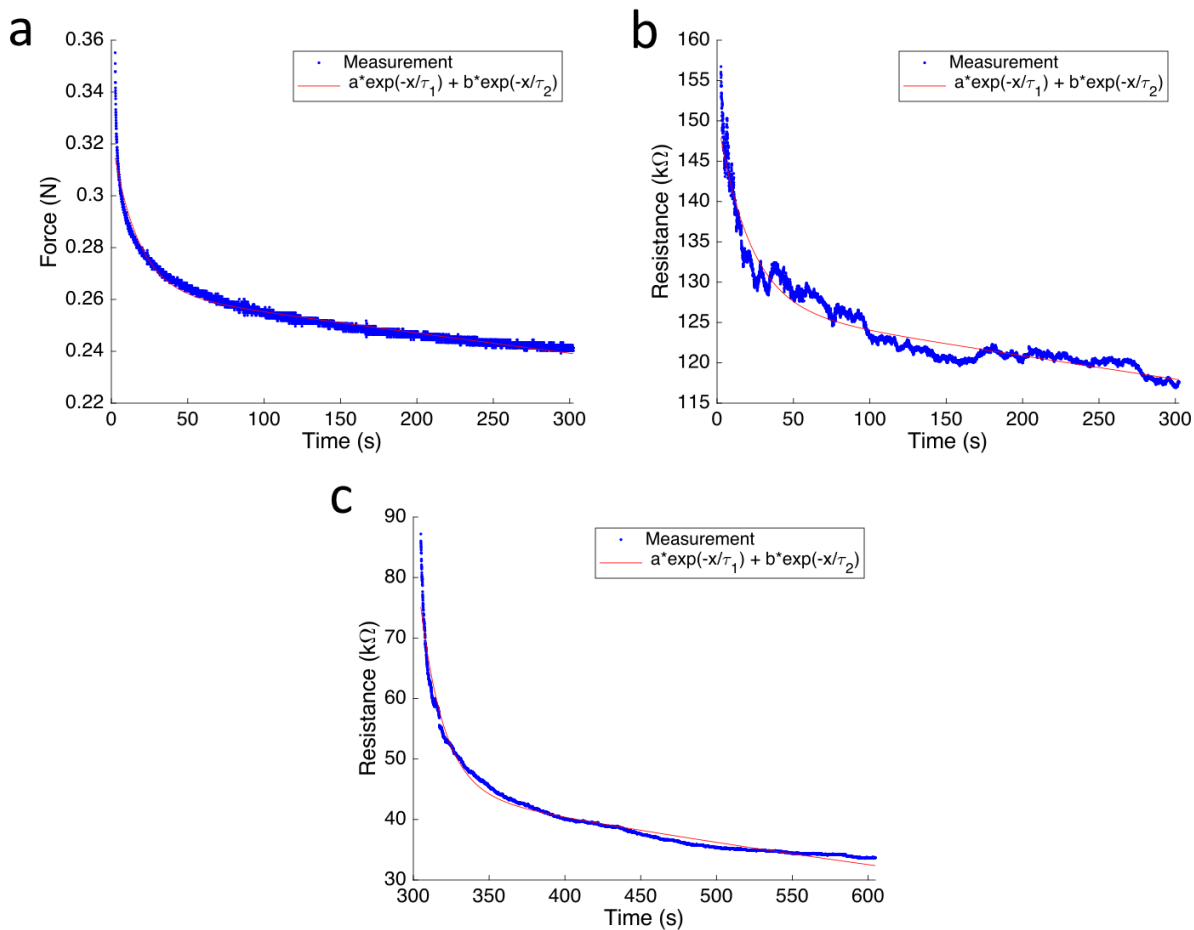


Figure S7. Fitting of (a) force and (b) resistance of I relaxation in Figure S6 and fitting of (c) resistance of II relaxation in Figure S6 with two exponential functions ($a \cdot e^{\frac{-x}{\tau_1}} + b \cdot e^{\frac{-x}{\tau_2}}$), resulting in a time constant $\tau_1 = 18.5 \pm 2.8$ s and $\tau_2 = 3100 \pm 1400$ s.

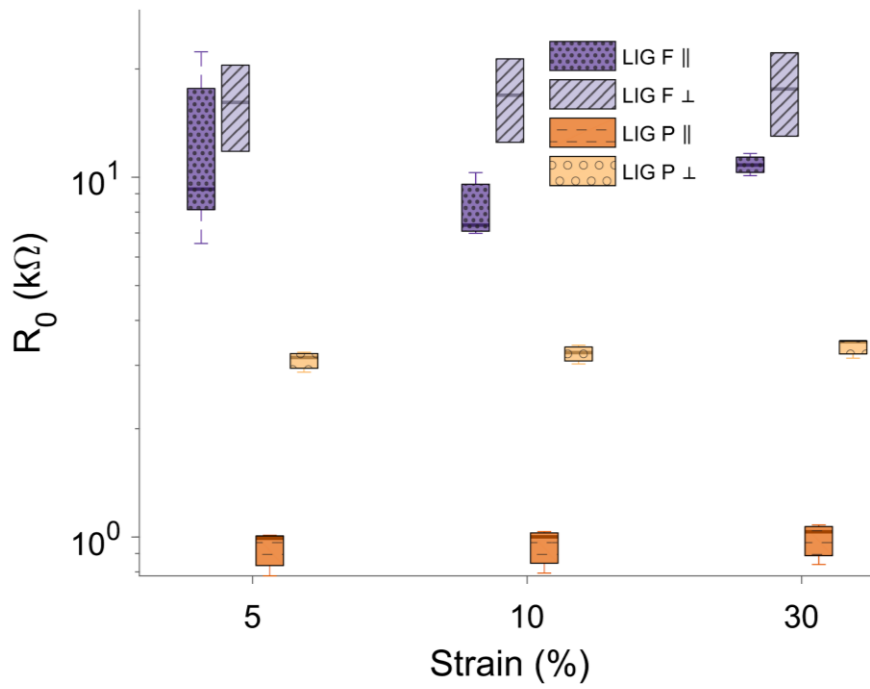


Figure S8. Starting resistance R_0 before each strain cycle for all LIG/MPU types.

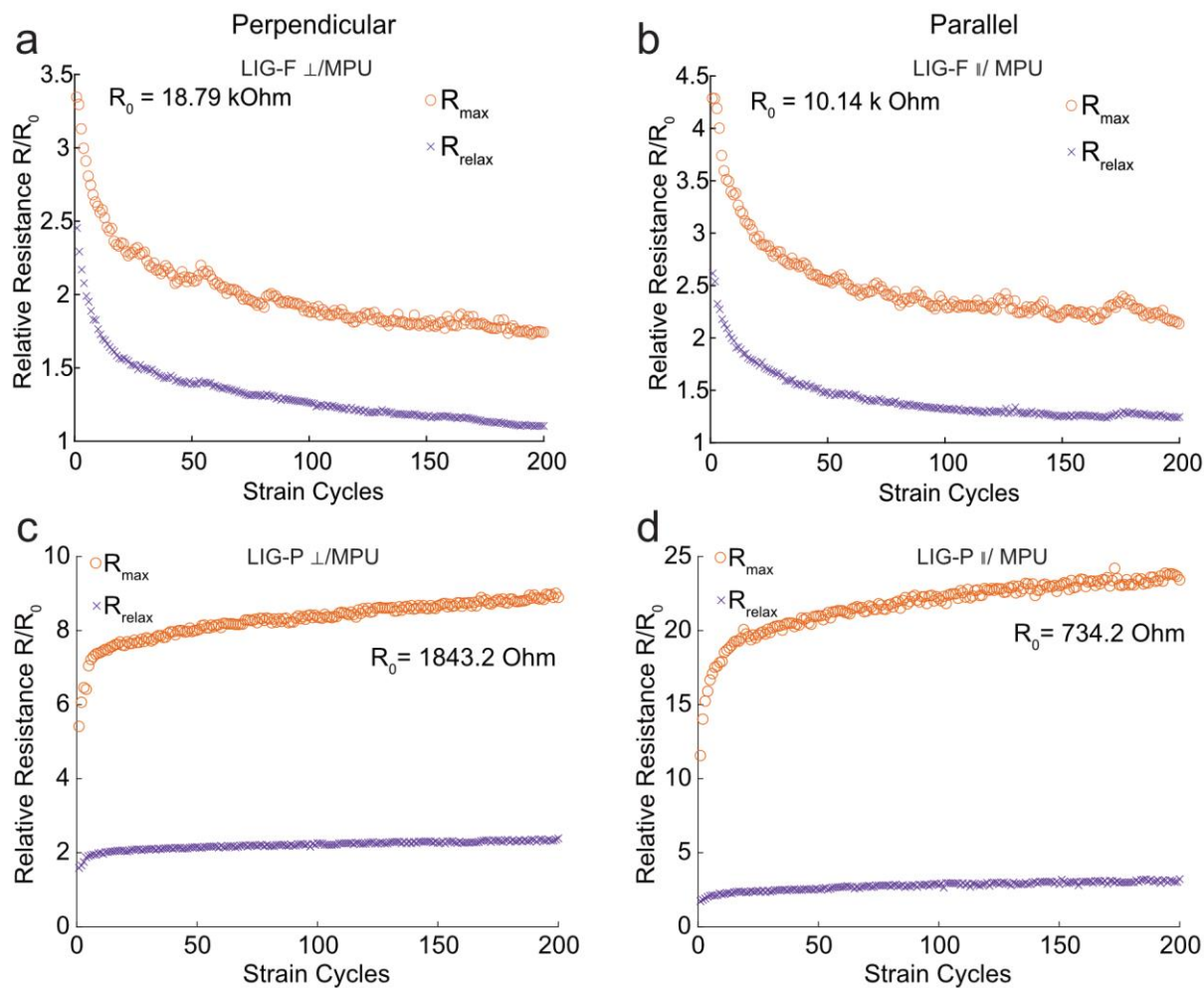


Figure S9. Change of maximum resistance R_{\max} and relaxed resistance R_{relax} over 200 cycles of tensile testing at 30% strain in the case of a) LIG-F \perp /MPU ($\phi = 90^\circ$), b) LIG-F \parallel /MPU ($\phi = 0^\circ$), c) LIG-P \perp /MPU ($\phi = 90^\circ$) and d) LIG-P \parallel /MPU ($\phi = 0^\circ$).

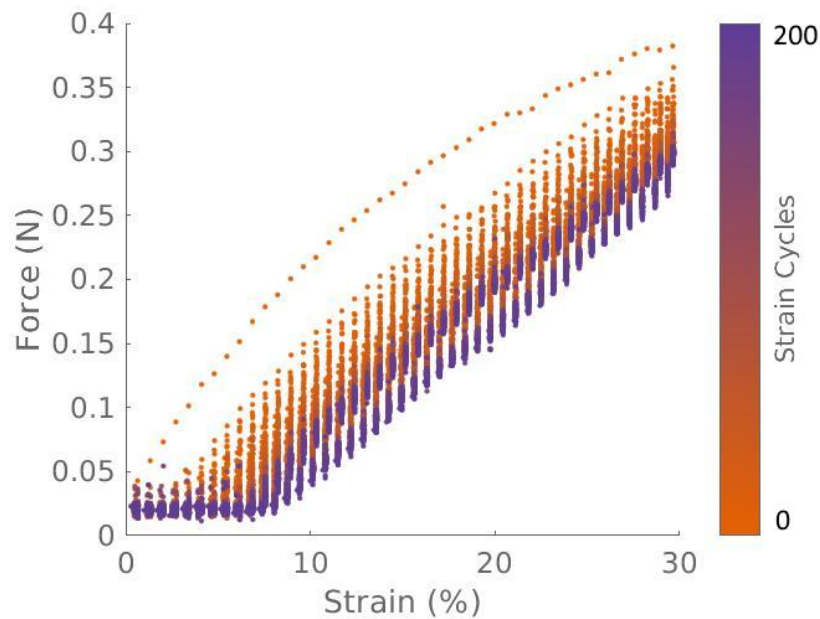


Figure S10. Force curve of MPU sample with a strain cycle of 30% imposed 200 times extracted from Figure S9.

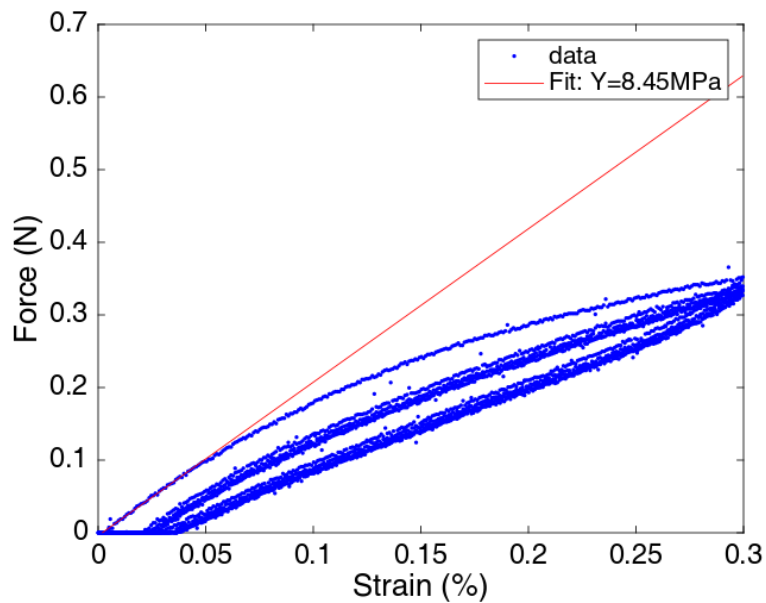


Figure S11. Fitting of Young's Modulus ($Y = 8.5 \pm 0.3$ MPa) for LIG-F/MPU with 30% strain.

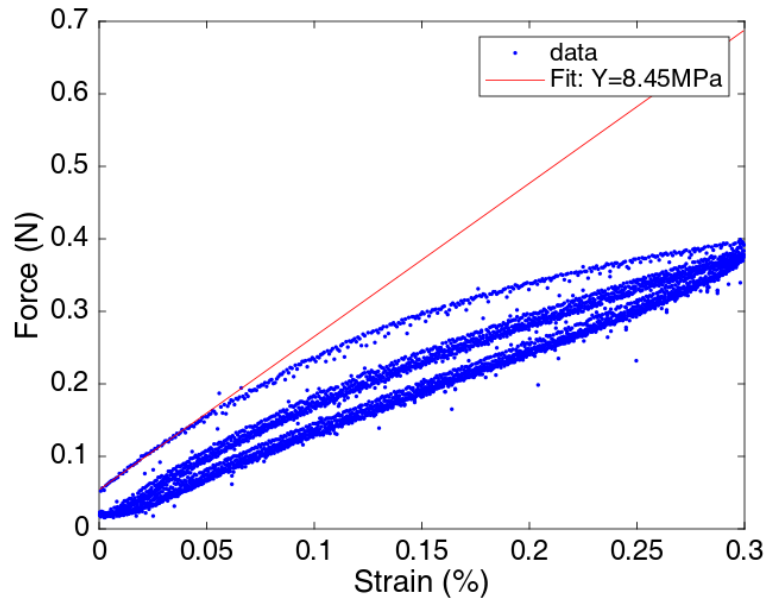


Figure S12. Fitting of Young's Modulus ($Y = 8.5 \pm 0.3$ MPa) for MPU with 30% strain.

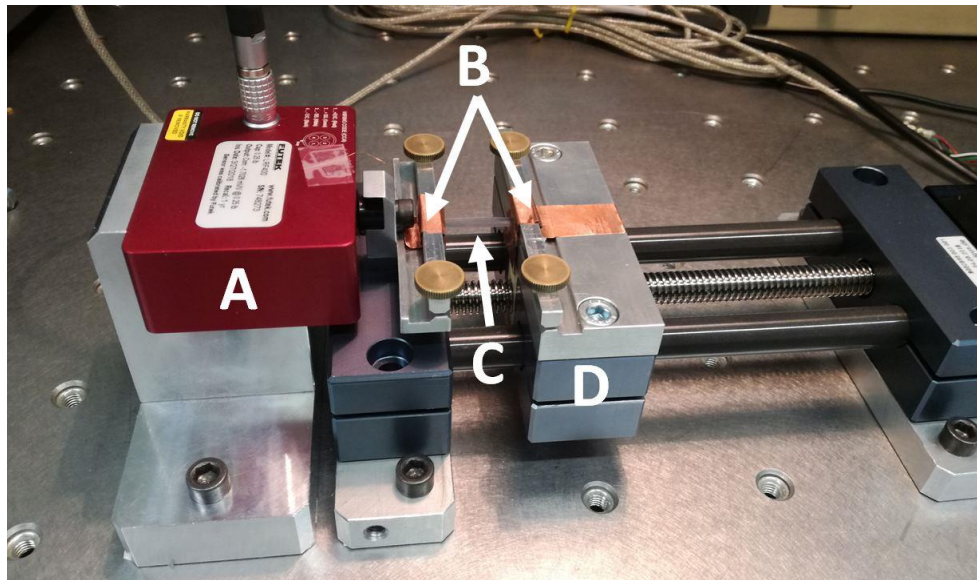


Figure S13. Custom tensile testing setup for mechanical and electrical characterization showing (A) load cell, (B) electrical contacts, (C) sample, (D) movable stage.

Calculation of laser fluence

The laser fluence H for each laser raster setting was calculated as

$$H = \frac{P \cdot P_{max} / 100}{s \cdot v \cdot PPI} \quad (S1)$$

where P is the set laser power (%) with respect to the maximal laser power $P_{max} = 30$ W, s is the theoretical laser spot size determined according to gaussian beam theory, v is the measured processing speed (depending on the sample size, $v \sim 110 \pm 10$ mm/s) and PPI the raster resolution.